

FEATURES

- Offset voltage: 2.5 mV max**
- Low input bias current: 1 pA max**
- Single-supply operation: 5 V to 16 V**
- Dual-supply operation: ± 2.5 V to ± 8 V**
- Low noise: 8 nV/ $\sqrt{\text{Hz}}$ @ 10 kHz**
- Wide bandwidth: 4 MHz**
- Rail-to-rail output**
- Unity-gain stable**
- Lead-free packaging**
- AD8666/AD8668 qualified for automotive applications**

APPLICATIONS

- Sensor amplification**
- Reference buffers**
- Medical equipment**
- Physiological measurements**
- Signal filters and conditioning**
- Consumer audio**
- Photodiode amplification**
- ADC driver**
- Level shifting circuits**

GENERAL DESCRIPTION

The AD866x family is single supply, rail-to-rail output amplifiers with low noise performance featuring an extended operating range with supply voltages up to 16 V. They also feature low input bias currents, wide signal bandwidth, and low input voltage and current noise. For lower offset voltage, choose the AD8661/AD8662/AD8664 family.

The combination of low offsets, very low input bias currents, and wide supply range make these amplifiers useful in a wide variety of cost sensitive applications normally associated with much higher priced JFET amplifiers. Systems using high impedance sensors, such as photo diodes, benefit from the combination of low input bias current, low noise, and low offset and bandwidth. The wide operating voltage range matches high performance ADCs and DACs. Audio applications and medical monitoring equipment can take advantage of the high input impedance, low voltage and current noise, wide bandwidth, and the lack of popcorn noise found in many other low input bias current amplifiers.

The AD866x family is specified over the extended industrial temperature range (-40°C to $+125^{\circ}\text{C}$). See the Ordering Guide for automotive models.

PIN CONFIGURATIONS

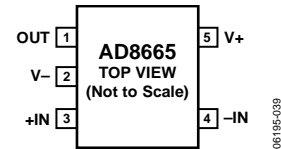


Figure 1. AD8665, 5-Lead SOT-23 (RJ-5)

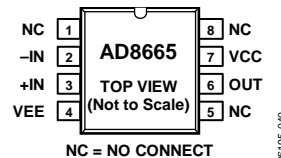


Figure 2. AD8665, 8-Lead SOIC_N (R-8)



Figure 3. AD8666, 8-Lead SOIC_N (R-8)



Figure 4. AD8666, 8-Lead MSOP (RM-8)



Figure 5. AD8668, 14-Lead TSSOP (RU-14)



Figure 6. AD8668, 14-Lead SOIC_N (R-14)

Rev. B

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REVISION HISTORY

7/11—Rev. A to Rev. B

Change to Features and General Description Sections	1
Updated Outline Dimensions	12
Changes to Ordering Guide	13
Added Automotive Products Section.....	13

10/06—Rev. 0 to Rev. A

Added AD8665	Universal
Added New Figure 1 and Figure 2, Renumbered Sequentially.....	1
Changes to Table 4.....	5
Changes to Figure 8, Figure 9, and Figure 11	6
Change to Figure 40	11
Updated Outline Dimensions	12
Changes to Ordering Guide	13

4/06—Rev 0: Initial Version

SPECIFICATIONS

$V_{DD} = 5.0\text{ V}$, $V_{CM} = V_{DD}/2$, $T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 1.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	V_{OS}	$V_{CM} = 2.5\text{ V}$ $V_{CM} = -0.1\text{ V to }+3.0\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.7	2.5	mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$		3.0	10	$\mu\text{V}/^\circ\text{C}$
Input Bias Current	I_B	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.2	1	pA
Input Offset Current	I_{OS}	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.1	0.5	pA
Input Voltage Range	V_{CM}	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$	-0.1		+3.0	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = -0.1\text{ V to }+3.0\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	84	100		dB
Large-Signal Voltage Gain	A_{VO}	$R_L = 2\text{ k}\Omega$, $V_O = 0.5\text{ V to }4.5\text{ V}$	68	145		V/mV
OUTPUT CHARACTERISTICS						
Output Voltage High	V_{OH}	$I_{OUT} = 1\text{ mA}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	4.88	4.93		V
Output Voltage Low	V_{OL}	$I_{OUT} = 1\text{ mA}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	4.86	50	85	V
Short-Circuit Output Current	I_{SC}			± 19	105	mV
Closed-Loop Output Impedance	Z_{OUT}	At 1 MHz, $A_V = 1$		50		Ω
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V_{DD} = 5.0\text{ V to }16\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	98	115		dB
Supply Current per Amplifier	I_{SY}	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$	94	1.1	1.4	dB
					2.0	mA
DYNAMIC PERFORMANCE						
Slew Rate	SR	$R_L = 2\text{ k}\Omega$		3.5		V/ μs
Gain Bandwidth Product	GBP			4		MHz
Phase Margin	Φ_M			70		Degrees
NOISE PERFORMANCE						
Peak-to-Peak Noise	$e_n\text{ p-p}$	0.1 Hz to 10 Hz		2.4		$\mu\text{V p-p}$
Voltage Noise Density	e_n	$f = 1\text{ kHz}$ $f = 10\text{ kHz}$		10		$\text{nV}/\sqrt{\text{Hz}}$
Channel Separation	CS	$f = 10\text{ kHz}$		-115		dB

AD8665/AD8666/AD8668

$V_{DD} = 16\text{ V}$, $V_{CM} = V_{DD}/2$, $T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 2.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	V_{OS}	$V_{CM} = 8\text{ V}$ $V_{CM} = -0.1\text{ V to }+14.0\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.6	2.5	mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$		3.0	10	$\mu\text{V}/^\circ\text{C}$
Input Bias Current	I_B	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.2	1	pA
Input Offset Current	I_{OS}	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$		0.1	0.5	pA
Input Voltage Range	V_{CM}	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$	-0.1		+14.0	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = -0.1\text{ V to }+14.0\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	90	110		dB
Large-Signal Voltage Gain	A_{VO}	$R_L = 2\text{ k}\Omega$, $V_O = 0.5\text{ V to }15.5\text{ V}$	80	255		dB
OUTPUT CHARACTERISTICS						
Output Voltage High	V_{OH}	$I_{OUT} = 1\text{ mA}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	15.94	15.96		V
Output Voltage Low	V_{OL}	$I_{OUT} = 1\text{ mA}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	15.90	22	40	V
Short-Circuit Output Current	I_{SC}			± 140	50	mV
Closed-Loop Output Impedance	Z_{OUT}	At 1 MHz, $A_V = 1$		50		mA
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V_{DD} = 5.0\text{ V to }16\text{ V}$ $-40^\circ\text{C} < T_A < +125^\circ\text{C}$	98	115		dB
Supply Current per Amplifier	I_{SY}	$-40^\circ\text{C} < T_A < +125^\circ\text{C}$	94	1.15	1.55	dB
DYNAMIC PERFORMANCE						
Slew Rate	SR	$R_L = 2\text{ k}\Omega$		3.5		$\text{V}/\mu\text{s}$
Gain Bandwidth Product	GBP			4		MHz
Phase Margin	Φ_M			73		Degrees
NOISE PERFORMANCE						
Peak-to-Peak Noise	$e_n\text{ p-p}$	0.1 Hz to 10 Hz		2.5		$\mu\text{V p-p}$
Voltage Noise Density	e_n	$f = 1\text{ kHz}$ $f = 10\text{ kHz}$		10		$\text{nV}/\sqrt{\text{Hz}}$
Channel Separation	CS	$f = 10\text{ kHz}$		-115		dB

ABSOLUTE MAXIMUM RATINGS

Table 3.

Parameter	Rating
Supply Voltage	18 V
Input Voltage	GND to V_{DD}
Differential Input Voltage	± 18 V
Output Short-Circuit to GND	Indefinite
Storage Temperature Range	-65°C to $+150^{\circ}\text{C}$
Operating Temperature Range	-40°C to $+125^{\circ}\text{C}$
Lead Temperature (Soldering, 60 sec)	300°C
Junction Temperature	150°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

THERMAL RESISTANCE

Table 4. Thermal Resistance

Package Type	θ_{JA}	θ_{JC}	Unit
5-Lead SOT-23 (RJ-5)	240	92	$^{\circ}\text{C}/\text{W}$
8-Lead SOIC_N (R-8)	158	43	$^{\circ}\text{C}/\text{W}$
8-Lead MSOP (RM-8)	210	45	$^{\circ}\text{C}/\text{W}$
14-Lead SOIC (R-14)	120	36	$^{\circ}\text{C}/\text{W}$
14-Lead TSSOP (RU-14)	180	35	$^{\circ}\text{C}/\text{W}$

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

TYPICAL PERFORMANCE CHARACTERISTICS



Figure 7. Input Offset Voltage Distribution



Figure 10. Input Bias Current vs. Temperature



Figure 8. V_{OS} Drift (TCV_{OS}) Distribution



Figure 11. Output Saturation Voltage vs. Load Current

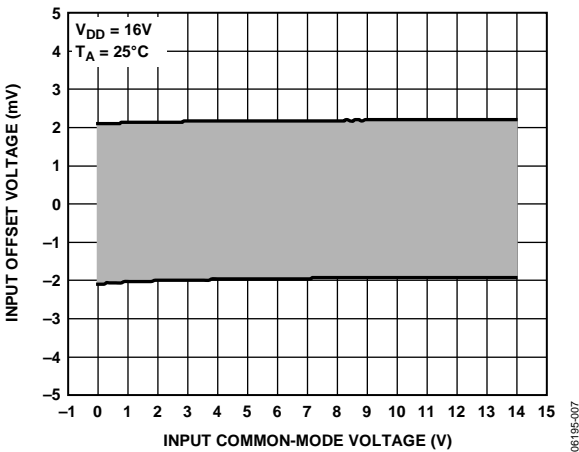


Figure 9. Offset Voltage vs. Common-Mode Voltage



Figure 12. Output Saturation Voltage vs. Temperature



Figure 13. Open-Loop Gain and Phase vs. Frequency

06195-011



Figure 16. Power Supply Rejection Ratio vs. Frequency

06195-014



Figure 14. Closed-Loop Output Impedance vs. Frequency

06195-012



Figure 17. Voltage Noise Density vs. Frequency

06195-015



Figure 15. Common-Mode Rejection Ratio vs. Frequency

06195-013



Figure 18. 0.1 Hz to 10 Hz Voltage Noise

06195-016

AD8665/AD8666/AD8668

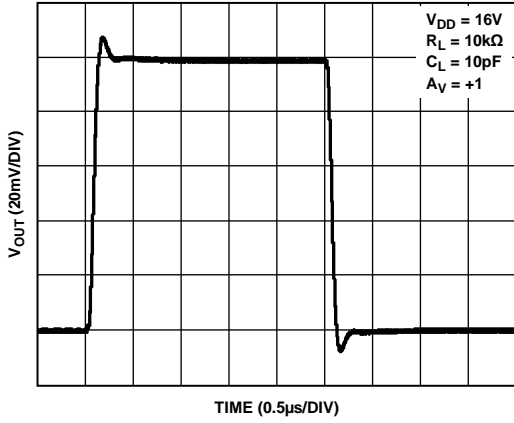


Figure 19. Small-Signal Transient Response

06195-017

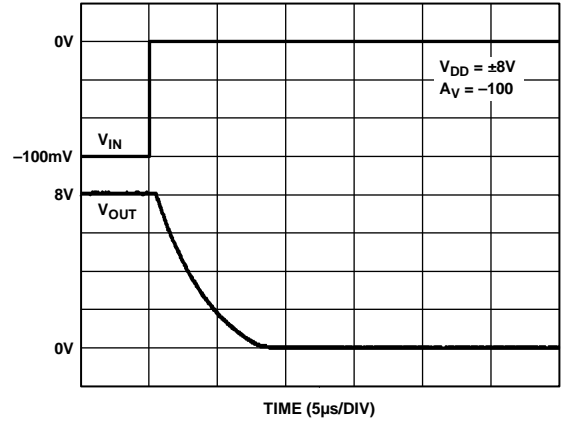


Figure 22. Positive Overload Recovery Time

06195-020

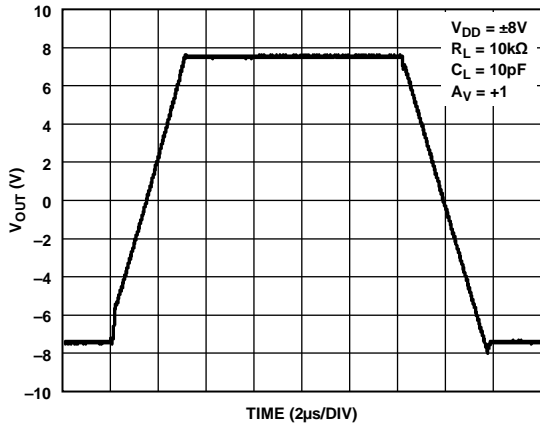


Figure 20. Large-Signal Transient Response

06195-018

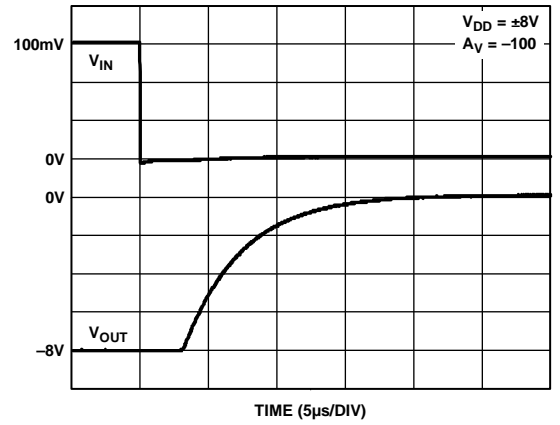


Figure 23. Negative Overload Recovery Time

06195-021

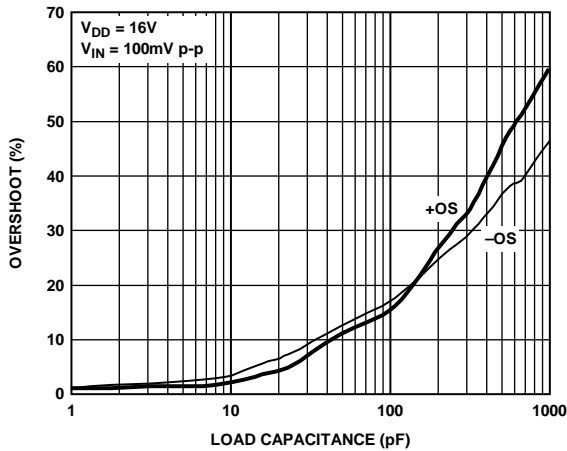


Figure 21. Small-Signal Overshoot vs. Load Capacitance

06195-019

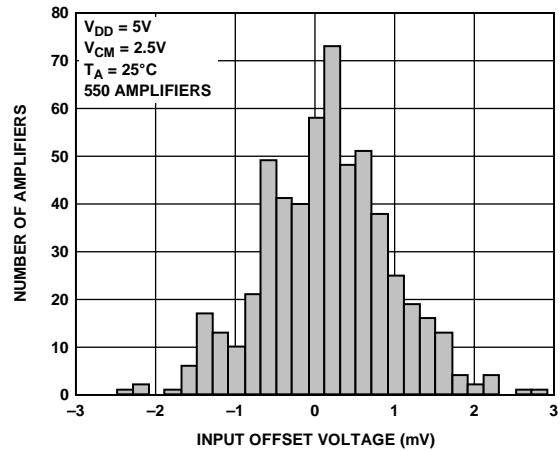


Figure 24. Input Offset Voltage Distribution

06195-022



Figure 25. V_{OS} Drift (TCV_{OS}) Distribution



Figure 28. Output Saturation Voltage vs. Temperature



Figure 26. Offset Voltage vs. Common-Mode Voltage

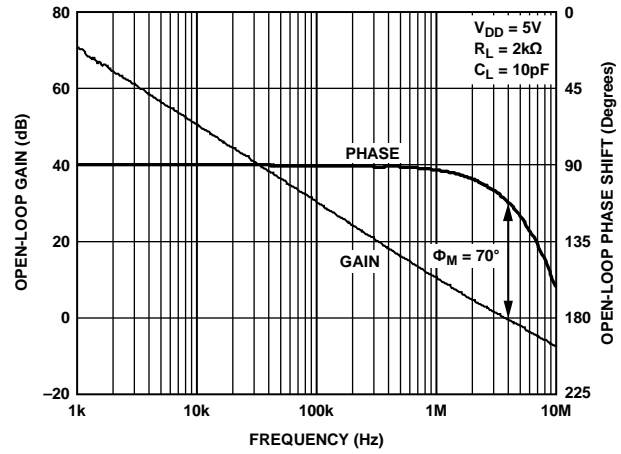


Figure 29. Open-Loop Gain and Phase vs. Frequency



Figure 27. Output Saturation Voltage vs. Load Current

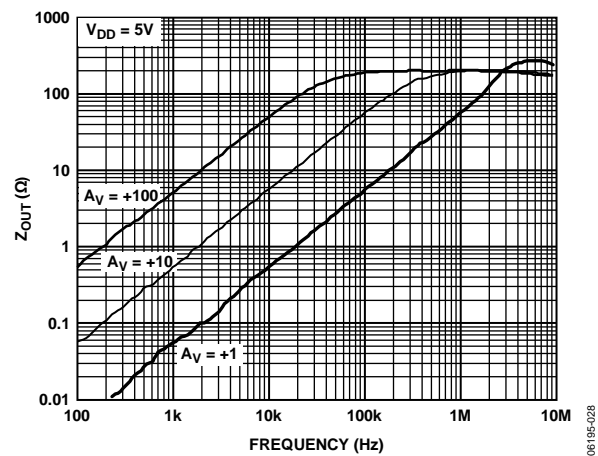


Figure 30. Closed-Loop Output Impedance vs. Frequency

AD8665/AD8666/AD8668



Figure 31. Common-Mode Rejection Ratio vs. Frequency

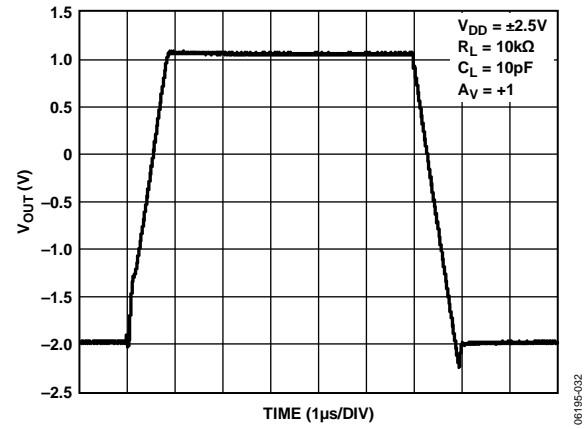


Figure 34. Large-Signal Transient Response

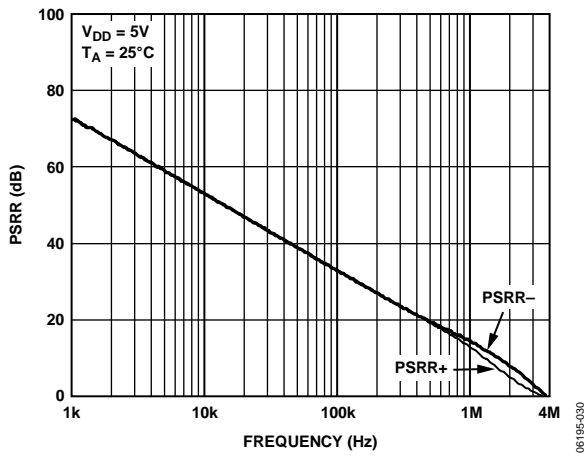


Figure 32. Power Supply Rejection Ratio vs. Frequency

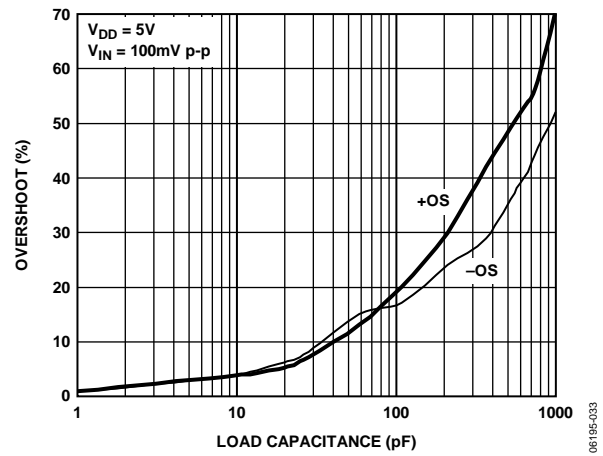


Figure 35. Small-Signal Overshoot vs. Load Capacitance

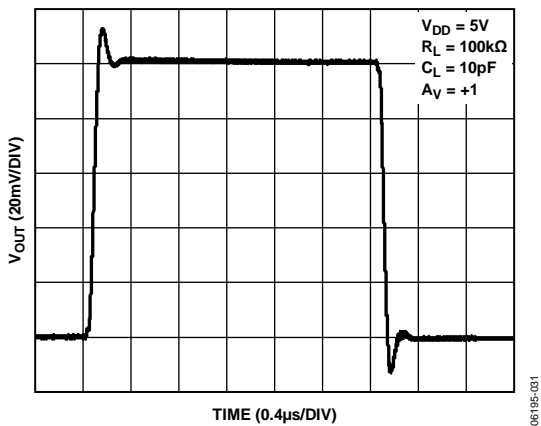


Figure 33. Small-Signal Transient Response

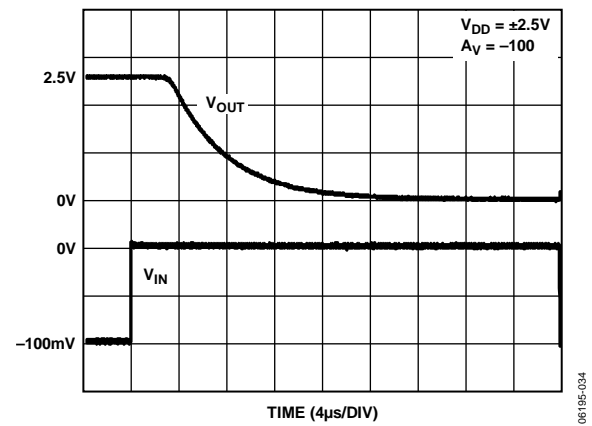


Figure 36. Positive Overload Recovery Time



Figure 37. Negative Overload Recovery Time



Figure 39. Supply Current vs. Supply Voltage



Figure 38. Supply Current vs. Temperature

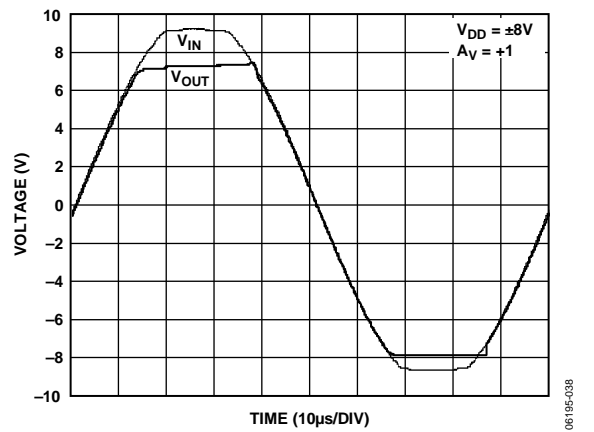
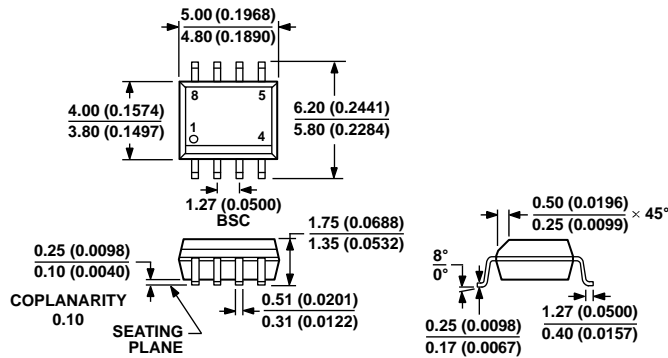


Figure 40. No Output Phase Reversal

OUTLINE DIMENSIONS

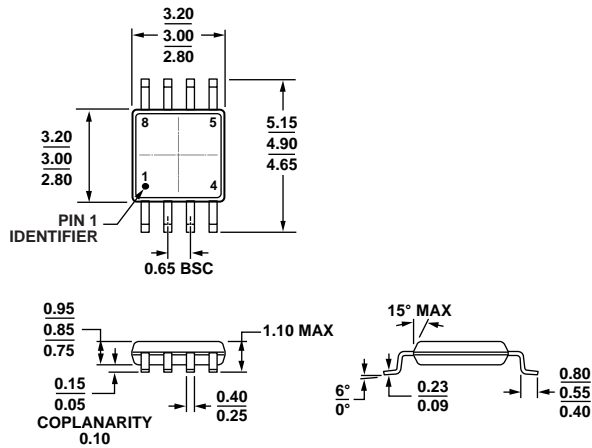


COMPLIANT TO JEDEC STANDARDS MS-012-AA
 CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
 (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
 REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 41. 8-Lead Standard Small Outline Package [SOIC_N]
 Narrow Body
 (R-8)

Dimensions shown in millimeters and (inches)

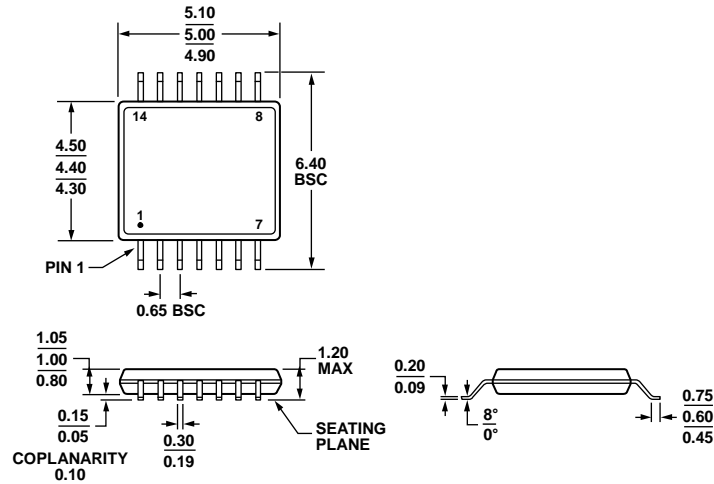
012407-A



COMPLIANT TO JEDEC STANDARDS MO-187-AA
 Figure 42. 8-Lead Mini Small Outline Package [MSOP]
 (RM-8)

Dimensions shown in millimeters

10-072008-B

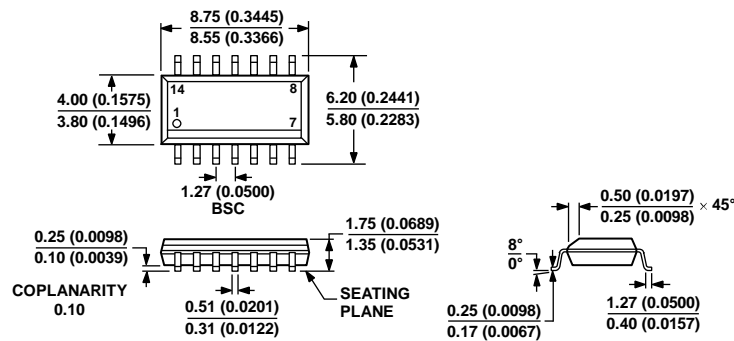


COMPLIANT TO JEDEC STANDARDS MO-153-AB-1

Figure 43. 14-Lead Thin Shrink Small Outline Package [TSSOP] (RU-14)

Dimensions shown in millimeters

061906-A



COMPLIANT TO JEDEC STANDARDS MS-012-AB
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 44. 14-Lead Standard Small Outline Package [SOIC_N] Narrow Body (R-14)

Dimensions shown in millimeters and (inches)

060606-A

AD8665/AD8666/AD8668



COMPLIANT TO JEDEC STANDARDS MO-178-AA

Figure 45. 5-Lead Small Outline Transistor Package [SOT-23] (RJ-5)

Dimensions shown in millimeters

11-01-2010-A

ORDERING GUIDE

Model ^{1,2}	Temperature Range	Package Description	Package Option	Branding
AD8665ARZ	-40°C to +125°C	8-Lead SOIC_N	R-8	
AD8665ARZ-REEL	-40°C to +125°C	8-Lead SOIC_N	R-8	
AD8665ARZ-REEL7	-40°C to +125°C	8-Lead SOIC_N	R-8	
AD8665ARJZ-R2	-40°C to +125°C	5-Lead SOT-23	RJ-5	A1B
AD8665ARJZ-REEL	-40°C to +125°C	5-Lead SOT-23	RJ-5	A1B
AD8665ARJZ-REEL7	-40°C to +125°C	5-Lead SOT-23	RJ-5	A1B
AD8666ARZ	-40°C to +125°C	8-Lead SOIC_N	R-8	
AD8666ARZ-REEL	-40°C to +125°C	8-Lead SOIC_N	R-8	
AD8666ARZ-REEL7	-40°C to +125°C	8-Lead SOIC_N	R-8	
AD8666ARMZ	-40°C to +125°C	8-Lead MSOP	RM-8	A16
AD8666ARMZ-REEL	-40°C to +125°C	8-Lead MSOP	RM-8	A16
AD8666WARZ-R7	-40°C to +125°C	8-Lead SOIC_N	R-8	
AD8666WARZ-RL	-40°C to +125°C	8-Lead SOIC_N	R-8	
AD8668ARZ	-40°C to +125°C	14-Lead SOIC_N	R-14	
AD8668ARZ-REEL	-40°C to +125°C	14-Lead SOIC_N	R-14	
AD8668ARZ-REEL7	-40°C to +125°C	14-Lead SOIC_N	R-14	
AD8668ARUZ	-40°C to +125°C	14-Lead TSSOP	RU-14	
AD8668ARUZ-REEL	-40°C to +125°C	14-Lead TSSOP	RU-14	
AD8668WARUZ-R7	-40°C to +125°C	14-Lead TSSOP	RU-14	
AD8668WARUZ-RL	-40°C to +125°C	14-Lead TSSOP	RU-14	

¹ Z = RoHS Compliant Model

² W = Qualified for Automotive Applications.

AUTOMOTIVE PRODUCTS

The AD8666W/AD8668W models are available with controlled manufacturing to support the quality and reliability requirements of automotive applications. Note that these automotive models may have specifications that differ from the commercial models; therefore, designers should review the Specifications section of this data sheet carefully. Only the automotive grade products shown are available for use in automotive applications. Contact your local Analog Devices account representative for specific product ordering information and to obtain the specific Automotive Reliability reports for these models.

NOTES

AD8665/AD8666/AD8668

NOTES

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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